

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE	
In re application of: Huilong Zhu	Date: January 9, 2007
Serial Number: 10/710,244	Examiner: Fazli Erdem
Filed: 06/29/2004	Group Art Unit: 2826
Title: Structures and Methods for Manufacturing P-Type MOSFET with Graded Embedded Silicon-Germanium Source-Drain and/or Extension	IBM Corporation D/18G, B/321, Zip 482 2070 Route 52 Hopewell Junction, NY 12533-6531

AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Responsive to the Office Action dated 10/10/2006, kindly amend the above-identified application as follows.